

PSMN075-100MSE

N-channel 100 V 71 m Ω standard level MOSFET in LFPAK33 designed specifically for PoE applications

6 March 2013 Product data sheet

1. General description

New standards and proprietary approaches are enabling the next generation of Power-over-Ethernet (PoE) systems capable of delivering up to 100W to each powered device (PD). Large screen LCD displays, 3G / 4G / Wi-Fi hot-spots and pantilt-zoom CCTV cameras, for example, are placing increased demands on the power sourcing equipment (PSE) in terms of "soft-start" procedures, resilience to short-circuits, thermal management and power density. Part of Nexperia's "NextPower Live" MOSFET portfolio, the PSMN075-100MSE has been designed specifically to compliment the latest PoE controllers, offering both superior linear mode operation and very low RDS(on) in a cost-effective, industry compatible, LFPAK33 package.

2. Features and benefits

- Enhanced forward biased safe operating area for superior linear mode operation
- Low Rdson for low conduction losses
- Ultra reliable LFPAK33 package no glue, no wires, 175°C
- Very low I_{DSS}

3. Applications

- IEEE802.3at and proprietary solutions (type 2)
- Suitable for PoE applications upto 30W
- Use PSMN040-100MSE for higher power requirements

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	100	V
I _D	drain current	T _j = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>		-	-	18	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	65	W
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ °C}; Fig. 12$		-	57	71	mΩ
Dynamic char	Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; V_{DS} = 50 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 14; Fig. 15$		-	5.3	-	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; V_{DS} = 50 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 14; Fig. 15$	-	16.4	-	nC
Avalanche Ru	ggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 18 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω ; unclamped; Fig. 3	-	-	25	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G T T
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN075-100MSE	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN075-100MSE	M75E10

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 175$ °C; $R_{GS} = 20$ kΩ	-	100	V

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Symbol	Parameter	Conditions	Min	Max	Unit
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 1</u>	-	18	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	13	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$; Fig. 4	-	74	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	65	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-drai	in diode				
Is	source current	T _{mb} = 25 °C	-	54	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	74	Α
Avalanche F	Ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_{D} = 18 A; $V_{sup} \le$ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3	-	25	mJ

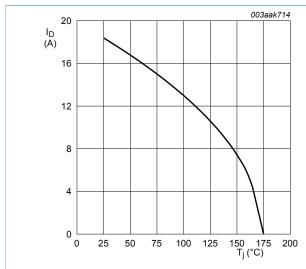


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

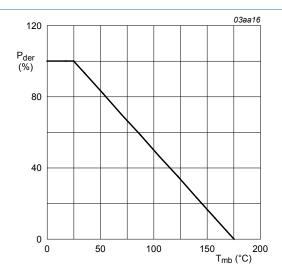


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

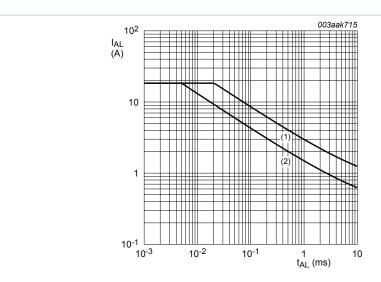


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j (int)} = 25$$
°C; (2) $T_{j (int)} = 100$ °C

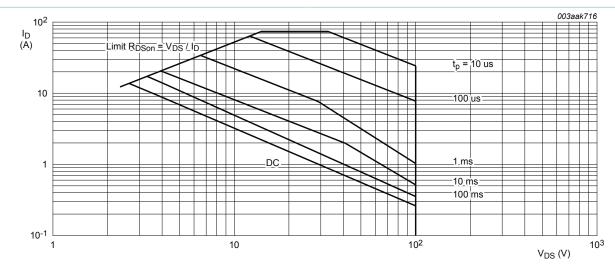


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

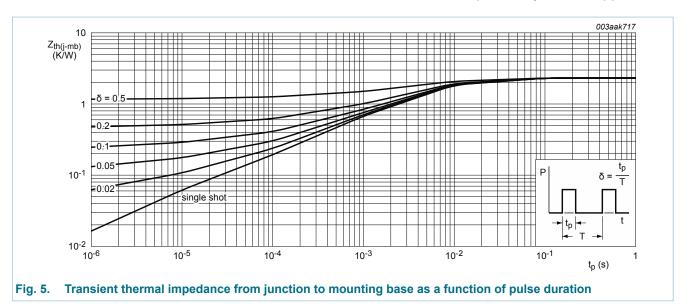
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	2.09	2.32	K/W

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Mir	Тур	Max	Unit
Static chara	acteristics		1			
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	10) -	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	90	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10; Fig. 11	2.3	3.3	4	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 175 °C; Fig. 10	1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = -55 °C; Fig. 10	-	-	4.6	V
I _{DSS} drain leakage current	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.01	1	μA
	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA	
I _{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; <u>Fig. 12</u>	-	57	71	mΩ
resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 100 °C; Fig. 13; Fig. 12	-	-	128	mΩ	
		V _{GS} = 10 V; I _D = 5 A; T _j = 175 °C; Fig. 13; Fig. 12	-	-	192	mΩ
R _G	gate resistance	f = 10 MHz	-	1.55	-	Ω

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics			1		
Q _{G(tot)}	total gate charge	I _D = 5 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	16.4	-	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$	-	12.9	-	nC
Q _{GS}	gate-source charge	I _D = 5 A; V _{DS} = 50 V; V _{GS} = 10 V;	-	3.1	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	2.1	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	1	-	nC
Q_{GD}	gate-drain charge	I _D = 5 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.3	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 5 A; V _{DS} = 50 V; T _j = 25 °C; Fig. 14; Fig. 15	-	4.3	-	V
C _{iss}	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 16$	-	773	-	pF
C _{oss}	output capacitance		-	66	-	pF
C _{rss}	reverse transfer capacitance		-	48	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 50 V; R_{L} = 10 Ω ; V_{GS} = 10 V;	-	5.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	5.8	-	ns
t _{d(off)}	turn-off delay time		-	12.4	-	ns
t _f	fall time		-	6.2	-	ns
Source-dra	in diode				-1	
V_{SD}	source-drain voltage	I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; <u>Fig. 17</u>	-	0.89	1.2	V
t _{rr}	reverse recovery time	$I_S = 5 \text{ A}$; $dI_S/dt = -100 \text{ A/}\mu\text{s}$; $V_{GS} = 0 \text{ V}$;	-	35.8	-	ns
Q _r	recovered charge	$V_{DS} = 50 \text{ V}; T_j = 25 \text{ °C}$	-	50.7	-	nC

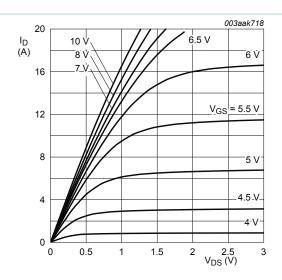


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



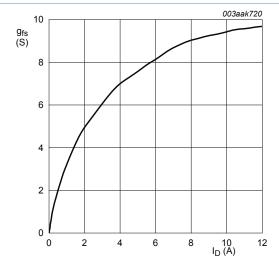


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25^{\circ}C; \ V_{DS} = 10V$$

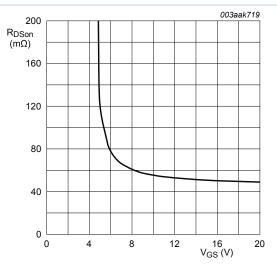


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; I_D = 5A$$

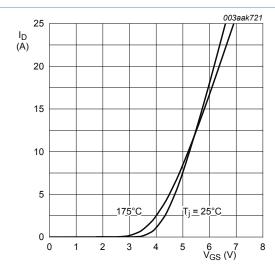


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

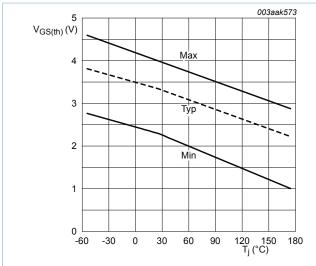


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; \ V_{DS} = V_{GS}$$

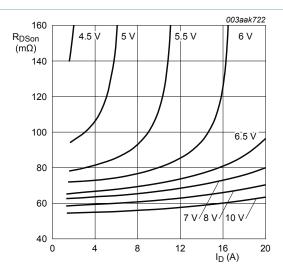


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

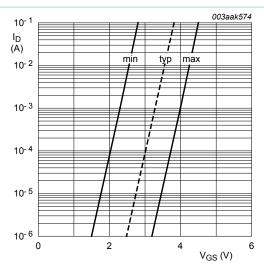


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25 \,^{\circ}C; V_{DS} = 5V$$

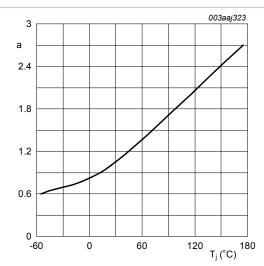


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon} \cos \alpha}$$

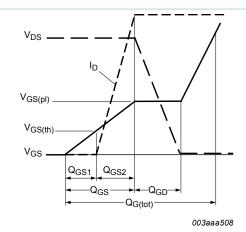


Fig. 14. Gate charge waveform definitions

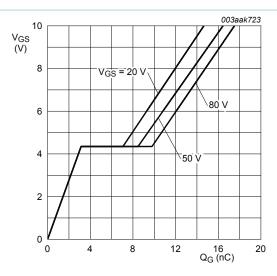


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 5A$$

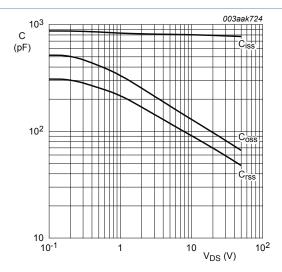
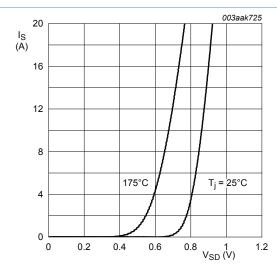


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source current as a function of source-drain as a function of drain-source voltage; typical values

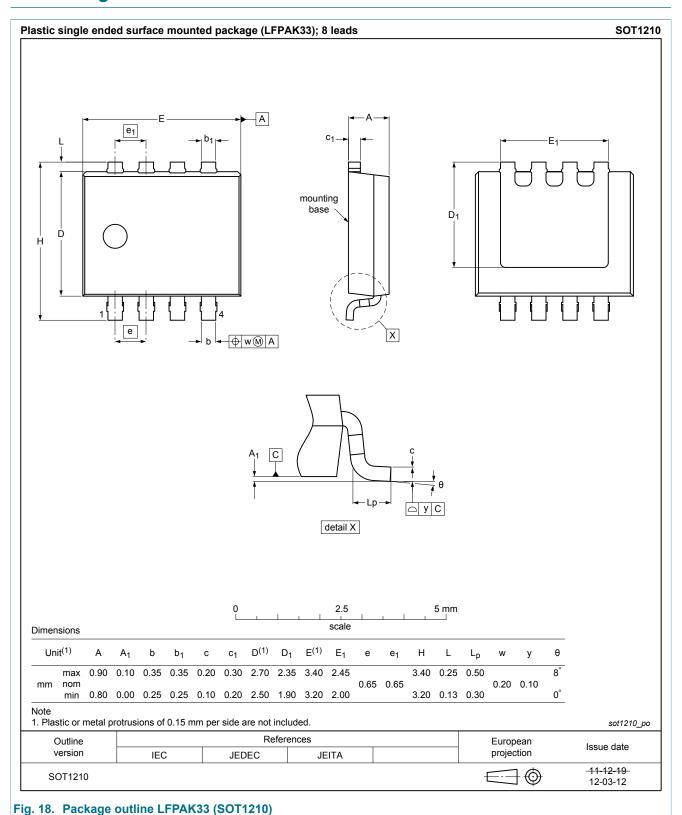
$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$



voltage; typical values

$$V_{GS} = 0V$$

11. Package outline



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